



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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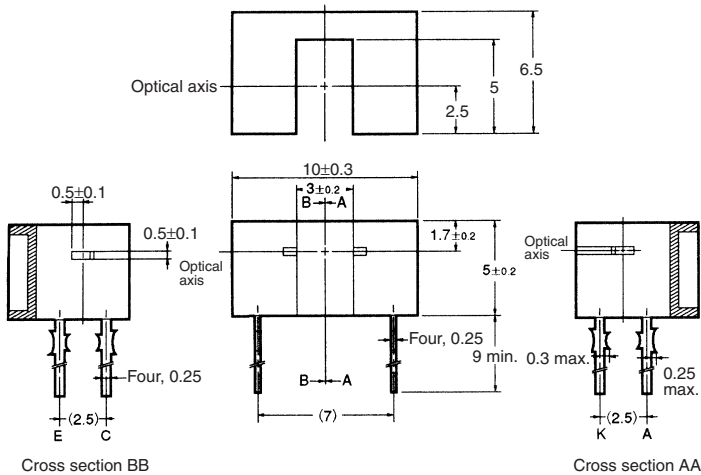


## Photomicrosensor (Transmissive) EE-SX1046

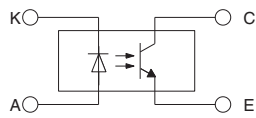
**⚠ Be sure to read *Precautions* on page 24.**

### ■ Dimensions

**Note:** All units are in millimeters unless otherwise indicated.



### Internal Circuit



Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

### ■ Features

- With a horizontal sensing aperture.
- PCB mounting type.
- High resolution with a 0.5-mm-wide aperture.

### ■ Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value
Emitter	Forward current	$I_F$ 50 mA (see note 1)
	Pulse forward current	$I_{FP}$ 1 A (see note 2)
	Reverse voltage	$V_R$ 4 V
Detector	Collector–Emitter voltage	$V_{CEO}$ 30 V
	Emitter–Collector voltage	$V_{ECO}$ ---
	Collector current	$I_C$ 20 mA
	Collector dissipation	$P_C$ 100 mW (see note 1)
Ambient temperature	Operating	$T_{opr}$ -25°C to 85°C
	Storage	$T_{stg}$ -30°C to 100°C
Soldering temperature	$T_{sol}$	260°C (see note 3)

- Note:**
1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
  2. The pulse width is 10  $\mu$ s maximum with a frequency of 100 Hz.
  3. Complete soldering within 10 seconds.

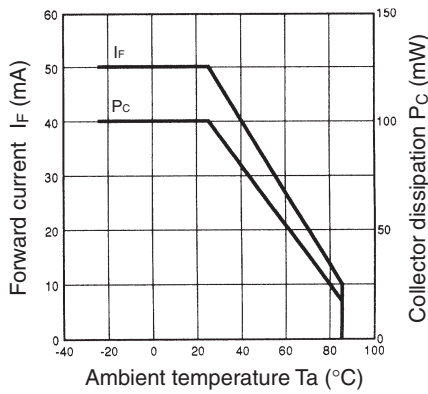
### ■ Electrical and Optical Characteristics (Ta = 25°C)

Item	Symbol	Value	Condition
Emitter	Forward voltage	$V_F$ 1.2 V typ., 1.5 V max.	$I_F = 30$ mA
	Reverse current	$I_R$ 0.01 $\mu$ A typ., 10 $\mu$ A max.	$V_R = 4$ V
	Peak emission wavelength	$\lambda_P$ 920 nm typ.	$I_F = 20$ mA
Detector	Light current	$I_L$ 1.2 mA min., 14 mA max.	$I_F = 20$ mA, $V_{CE} = 5$ V
	Dark current	$I_D$ 2 nA typ., 200 nA max.	$V_{CE} = 10$ V, 0 lx
	Leakage current	$I_{LEAK}$ ---	---
	Collector–Emitter saturated voltage	$V_{CE(sat)}$ 0.1 V typ., 0.4 V max.	$I_F = 20$ mA, $I_L = 0.1$ mA
	Peak spectral sensitivity wavelength	$\lambda_P$ 850 nm typ.	$V_{CE} = 10$ V
Rising time	$t_r$	4 $\mu$ s typ.	$V_{CC} = 5$ V, $R_L = 100 \Omega$ , $I_L = 5$ mA
Falling time	$t_f$	4 $\mu$ s typ.	$V_{CC} = 5$ V, $R_L = 100 \Omega$ , $I_L = 5$ mA

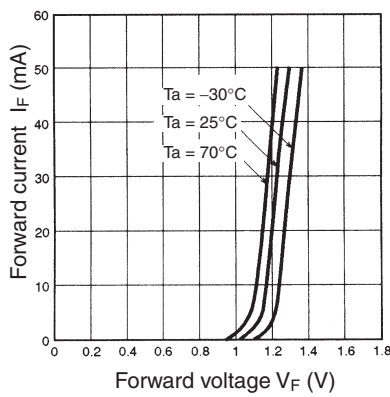


■ Engineering Data

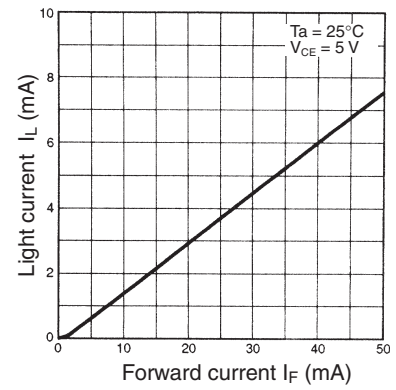
Forward Current vs. Collector Dissipation Temperature Rating



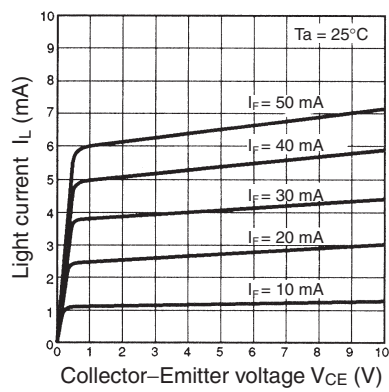
Forward Current vs. Forward Voltage Characteristics (Typical)



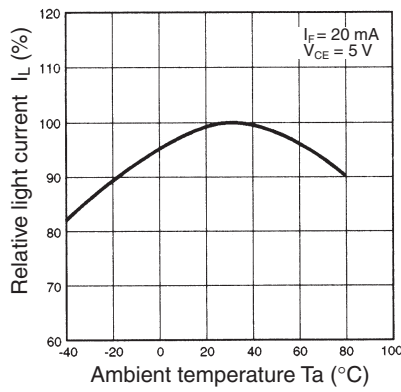
Light Current vs. Forward Current Characteristics (Typical)



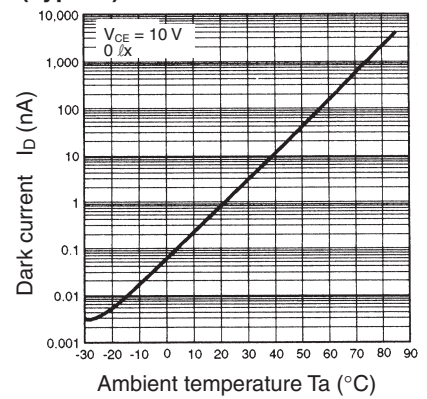
Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



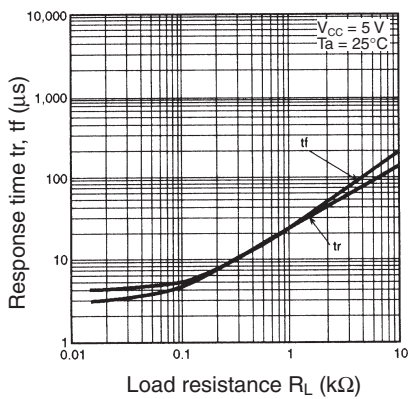
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



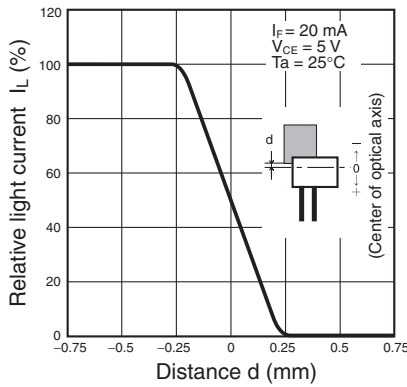
Dark Current vs. Ambient Temperature Characteristics (Typical)



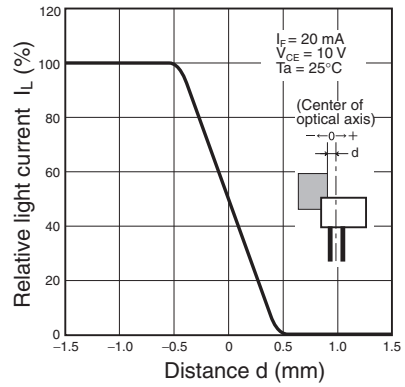
Response Time vs. Load Resistance Characteristics (Typical)



Sensing Position Characteristics (Typical)



Sensing Position Characteristics (Typical)



Response Time Measurement Circuit

